AMENDMENT TO THE CLAIMS

Please amend Claim 43 as follows:

Claims 1-42 (canceled)

Claim 43: (currently amended) A thin film <u>flexible</u> transistor backplane; <u>for use in electronic-ink</u> <u>based display devices</u>, <u>said thin film flexible transistor backplane</u> comprising:

- a polyimide substrate <u>having a deposition surface and thickness to exhibit flexible</u> characteristics in at least one dimension:
- a first passivation layer deposited on a the deposition surface of the said polyimide substrate;

an array of gate electrodes and gate lines patterned on the said passivation layer;

- a gate insulating layer deposited over the array of gate electrodes and gate lines;
- a semiconducting channel layer deposited over the said gate insulating layer;
- a contact layer deposited on and in contact with the said semiconducting channel layer; and

an array of source electrodes, drain electrodes, lines and pads fabricated on and in contact with the <u>said</u> contact layer.

Claims 44-95 (canceled)